

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor dates sheds, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor dates sheds and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use on similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor and its officers, employees, subsidiaries, affliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or i, directly or indirectly, any lange of the applicatio customer's to unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the

May 2010



KSC5305D NPN Silicon Transistor

Features

- High Voltage High Speed Power Switch Application
- · Built-in Free-wheeling Diode makes efficient anti saturation operation
- Suitable for half bridge light ballast Applications
- No need to interest an h_{FE} value because of low variable storage-time spread even though corner spirit product
- · Low base drive requirement



Absolute Maximum Ratings T_a = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CBO}	Collector Base Voltage	800	V	
V _{CEO}	Collector Emitter Voltage	400	V V	
V _{EBO}	Emitter Base Voltage	12		
Ι _C	Collector Current (DC)	5	А	
I _{CP}	*Collector Current (Pulse)	10	А	
Ι _Β	Base Current (DC)	2	А	
I _{BP}	*Base Current (Pulse)	4	А	
P _C Power Dissipation (T _C =25°C)		75	W	
Т _Ј	Γ _J Junction Temperature 150		°C	
T _{STG}	Storage Temperature	- 65 to 150	°C	

* Pulse Test : Pulse Width = 5mS, Duty cycles \leq 10%

Thermal Characteristics

Symbol	Parameter		Rating	Units	
R _{θjc}	Thermal Resistance	Junction to Case	1.65	°C/W	
$R_{ heta ja}$		Junction to Ambient	62.5	°C/W	

© 2010 Fairchild Semiconductor Corporation KSC5305D Rev. A2

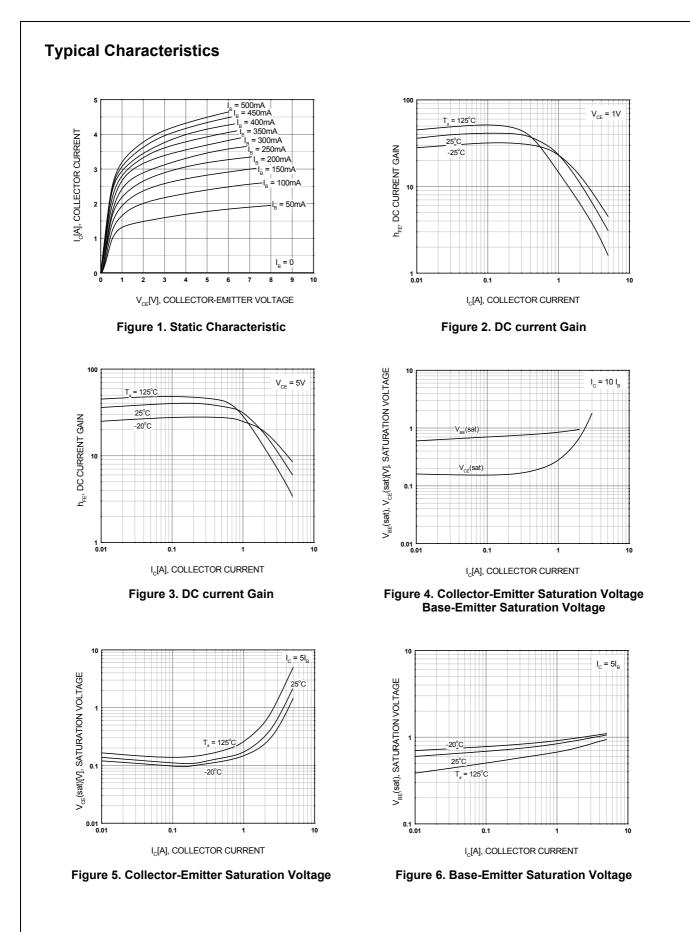
www.fairchildsemi.com

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =1mA, I _E =0	800	-	-	V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =5mA, I _B =0	400	-	-	V
BV_{EBO}	Emitter-Base Breakdown Voltage	I _E =1mA, I _C =0	12	-	-	V
I _{CBO}	Collector Cut-off Current	V _{CB} =500V, I _E =0	-	-	10	μA
I _{EBO}	Emitter Cut-off Current	V _{EB} = 9V, I _C = 0	-	-	10	μA
h _{FE1} h _{FE2}	DC Current Gain	V _{CE} =1V, I _C =0.8A V _{CE} =1V, I _C =2A	22 8	-	-	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =0.8A, I _B =0.08A I _C =2A, I _B =0.4A	-	-	0.4 0.5	V V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =0.8A, I _B =0.08A I _C =2A, I _B =0.4A	-	-	1.0 1.0	V V
C _{ob}	Output Capacitance	V _{CB} =10V, f=1MHz	-	-	75	pF
t _{ON}	Turn On Time	V_{CC} =300V, I _C =2A, I _{B1} =0.4A, I _{B2} =-1A, R _L =150Ω	-	-	150	ns
t _{STG}	Storage Time		-	-	2	μS
t _F	Fall Time		-	-	0.2	μS
t _{STG}	Storage Time	V _{CC} =15V, V _Z =300V,	-	-	2.25	μS
t _F	Fall Time	I _C =2A, I _{B1} =0.4A, I _{B2} =-0.4A, L _C =200μH	-	-	150	ns
V _F	Diode Forward Voltage	I _F =1A	-	-	1.5	V
		I _F =2A	-	-	1.6	V
t _{rr}	* Reverse recovery time	I _F =0.4A	-	800	-	ns
	(di/dt = 10A/µs)	I _F =1A I _F =2A	-	1.4 1.9	-	μS μS

Electrical Characteristics T_a=25°C unless otherwise noted

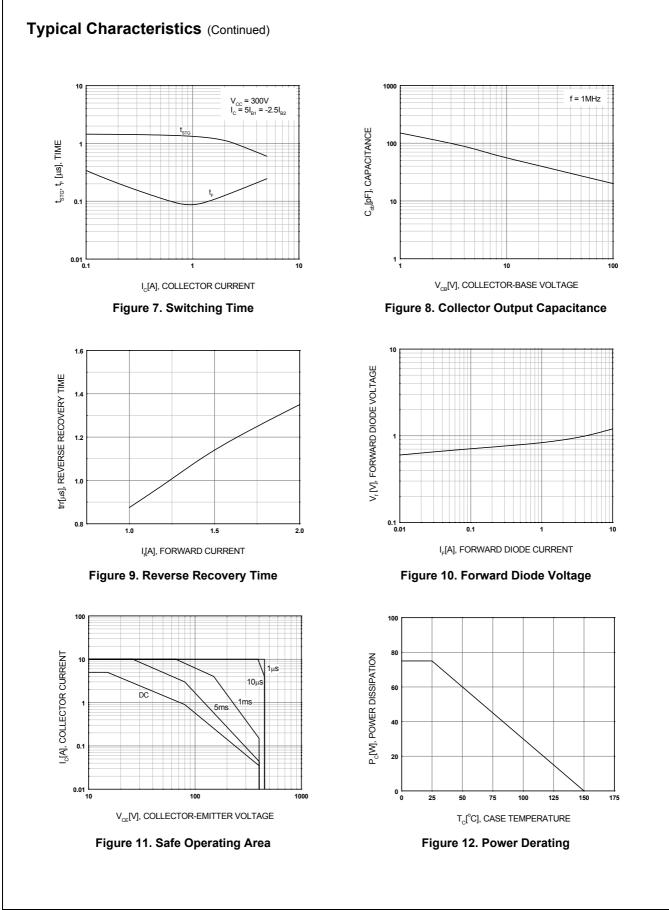
* Pulse Test : Pulse Width = 5mS, Duty cycles \leq 10%

KSC5305D — NPN Silicon Transistor

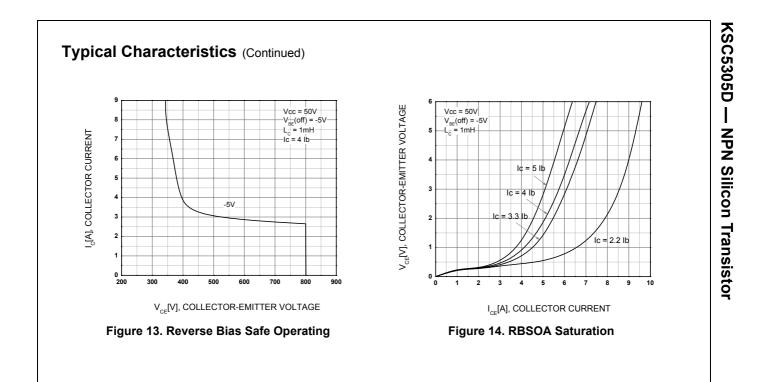


© 2010 Fairchild Semiconductor Corporation KSC5305D Rev. A2

www.fairchildsemi.com



© 2010 Fairchild Semiconductor Corporation KSC5305D Rev. A2





ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC